



### **74AHCT595**

#### **8-BIT SHIFT REGISTER 8-BIT OUTPUT REGISTER**

### **Description**

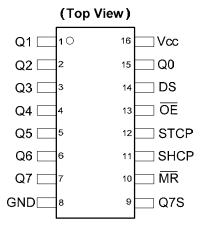
The 74AHCT595 is an advanced high speed CMOS device that is designed to be pin compatable with 74LS low power Schottky types.

An eight bit shift register accepts data from the serial input (DS) on each positive transition of the shift register clock (STCP). When asserted low, the reset function  $(\overline{MR})$  sets all shift register values to zero and is independent of all clocks.

Data from the input serial shift register is placed in the output register with a rising pulse on the storages resister clock (SHCP). With the output enable  $(\overline{OE})$  asserted low the 3-state outputs Q0-Q7 become active and present.

All registers capture data on rising edge and change output on the falling edge. If both clocks are connected together, the input shift register is always one clock cycle ahead of the output register.

### **Pin Assignments**



SO-16 / TSSOP-16

#### **Features**

- Supply Voltage Range from 4.5V to 5.5V
- Sinks or sources 8mA at V<sub>CC</sub> = 4.5V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
  - Exceeds 200-V Machine Model (A115-A)
  - Exceeds 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Applications**

- General Purpose Logic
- Serial to Parallel Data conversion
- Capture and hold data for extended periods of time.
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed.
- · Wide array of products such as:
  - Computer peripherals
  - Appliances
  - Industrial control

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

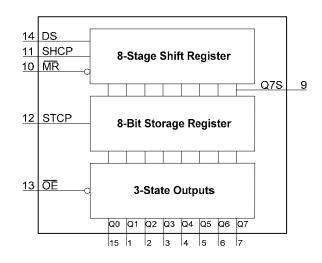
Click here for ordering information, located at the end of datasheet



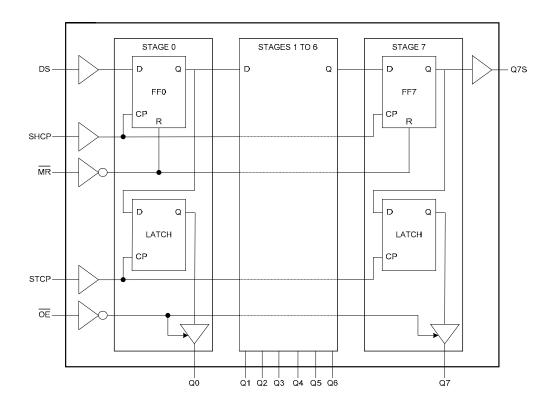
## **Pin Descriptions**

Pin Number	Pin Name	Description
1	Q1	Parallel Data Output 1
2	Q2	Parallel Data Output 2
3	Q3	Parallel Data Output 3
4	Q4	Parallel Data Output 4
5	Q5	Parallel Data Output 5
6	Q6	Parallel Data Output 6
7	Q7	Parallel Data Output 7
8	GND	Ground
9	Q7S	Serial Data Output
10	MR	Master Reset Input
11	SHCP	Shift Register Clock Input
12	STCP	Storage Register Clock Input
13	ŌĒ	Output Enable Input
14	DS	Serial Data Input
15	Q0	Parallel Data Output 0
16	Vcc	Supply Voltage

# **Functional Diagram**



## **Logic Diagram**



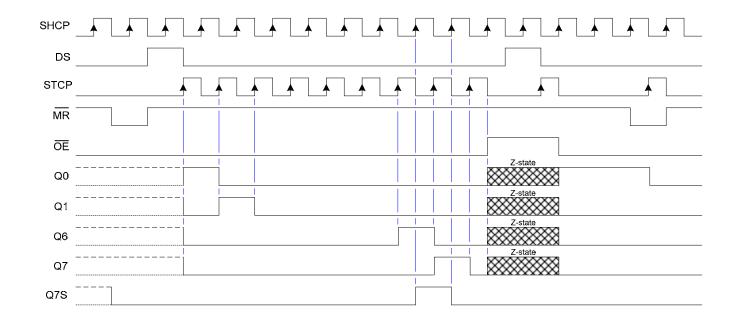


# **Functional Description and Timing Diagram**

	Con	trol		Input	Output		Firmation
SHCP	STCP	OE	MR	DS	Q7S	Qn	Function
Х	Х	L	L	-	L	NC	Low-level asserted on MR clears shift register. Storage register is unchanged
Х	1	L	L	-	L	L	Empty shift register transferred to storage register
X	Х	Н	L	_	L	Z	Shift register remains clear;: All Q ouputs in Z state.
<b>↑</b>	х	L	Н	_	Q6S NC HIGH is shifted into first stage of Shift Register Contents of each register shifted to next register The content of Q6S has been shifted to Q7S and now appears		HIGH is shifted into first stage of Shift Register Contents of each register shifted to next register The content of Q6S has been shifted to Q7S and now appears on device pin Q7S
Х	1	L	Н	-	NC	QnS	Contents of shift register copied to storage register. With output now in active state the storage resister contents appear on Q outputs.
<b>↑</b>	1	L	Н	-	Q6S	QnS	Contents of shift register copied to output register then shift register shifted.

H=HIGH voltage state L=LOW voltage state ↑=LOW to HIGH transition X= don't care – high or low (not floating) NC= No change

Z= high-impedance state





## Absolute Maximum Ratings (Note 4) (@TA = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
$V_{CC}$	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
Vo	Voltage applied to output in high or low state	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < -0.5V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> <-0.5V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> > V <sub>CC</sub> +0.5V	20	mA
Io	Continuous output current	±25	mA
Icc	Continuous current through Vcc or GND	75	mA
I <sub>GND</sub>	Continuous current through Vcc or GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>TOT</sub>	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

## Recommended Operating Conditions (Note 5) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	_	4.5	5.5	V
VI	Input Voltage	_	0	5.5	V
Vo	Output Voltage	Active Mode	0	$V_{CC}$	V
Δt/ΔV	Input transition rise or fall rate	V <sub>CC</sub> = 4.5V to 5.5V	-	20	ns/V
T <sub>A</sub>	Operating free-air temperature	-	-40	+125	°C

Note: 5. Unused inputs should be held at  $V_{CC}$  or Ground.

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V	TA	= +25°	С	T <sub>A</sub> = -40°	C to +85°C	T <sub>A</sub> = -40°	C to +125°C	Unit	
Symbol	Farameter	rest conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Oilit	
V <sub>IH</sub>	High-Level Input Voltage	_	4.5V to 5.5V	2.0	-	-	2.0	=	2.0	_	٧	
V <sub>IL</sub>	Low-Level Input voltage	_	4.5V to 5.5V	-	_	0.8	-	0.8	-	0.8	٧	
V	High-Level	I <sub>OH</sub> = -50μA	4.5V	4.4	4.5	-	4.4	-	4.4	-	V	
V <sub>OH</sub>	Output Voltage	I <sub>OH</sub> = -8mA	4.50	3.94	_	-	3.80	-	3.70	-	ľ	
	Low-Level	I <sub>OL</sub> = 50μA	4.5V	-	0	0.1	-	0.1	-	0.1	V	
V <sub>OL</sub>	Output Voltage Ic	Output Voltage I <sub>OL</sub> = 8n	I <sub>OL</sub> = 8mA	4.50	-	_	0.36	-	0.44	-	0.55	V
l <sub>l</sub>	Input Current	V <sub>I</sub> =GND to 5.5V	0 to 5.5V	-	0.1	± 1	-	± 1	=	± 2	μA	
l <sub>OZ</sub>	Z-state Leakage Current	$V_O = V_{CC}$ or GND $\overline{OE} = HIGH$	5.5V	i	_	± 0.25	-	2.5	-	10	μA	
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_O = 0$	5.5V	-	_	4.0	-	40	-	80	μA	
Δl <sub>CC</sub>	Additional Supply Current per Input	V <sub>I</sub> = Vcc -2.1V I <sub>O</sub> = 0	4.5V to 5.5V	-	=	1.35	-	1.5		1.5	mA	
Ci	Input Capacitance	$V_i = V_{CC}$ or GND	5.5V		4	10	-	10	=	10	pF	



# **Switching Characteristics**

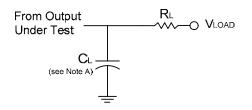
Symbol /	Director.	Took Conditions	.,	T <sub>A</sub> = +25°C			-40°C t	o +85°C	-40°C to +125°C		11:4:4
Parameter	Pins	Test Conditions	V <sub>CC</sub>	Min	Тур	Max	Min	Max	Min	Max	Unit
f <sub>MAX</sub> Maximum Frequency	SHCP or STCP	Figure 1	4.5V to 5.5V	130	170	_	110	_	90	_	MHz
	SHCP HIGH or LOW	Figure 1	4.5V to 5.5V	5.0	-	-	5.0	=	5.0	=	
t <sub>W</sub> Pulse Width	STCP HIGH or LOW	Figure 1	4.5V to 5.5V	5.0	=	_	5.0	=	5.0	=	ns
	MR LOW	Figure 1	4.5V to 5.5V	5.0	_	-	5.0	_	5.0	_	
tsu	DS to SHCP	Figure 1	4.5V to 5.5V	3.0	_	-	3.0	_	3.0	_	ns
Set-up Time	SHCP to STCP	Figure 1	4.5V to 5.5V	5.0	_	-	5.0	_	5.0	_	ns
t <sub>H</sub> Hold Time	DS to SHCP	Figure 1	4.5V to 5.5V	2.0	-	_	2.0	-	2.0	-	ns
t <sub>REC</sub> Recovery Time	MR to SHCP	Figure 1	4.5V to 5.5V	3.0	-	-	3.0	_	3.0	_	ns
	SHCP to Q7S	Figure 1 $C_L = 15pF$	4.5V to 5.5V	-	3.8	8.2	1.0	9	1.0	10	- ns
		Figure 1 $C_L = 50pF$	4.5V to 5.5V	-	5.2	10	1.0	11	1.0	12	
t <sub>PD</sub>	STCP to Qn	Figure 1 $C_L = 15pF$	4.5V to 5.5V	=	4	7.4	1.0	8.5	1.0	9.5	nc
Propagation Delay		Figure 1 $C_L = 50pF$	4.5V to 5.5V	=	5.3	9	1.0	10.5	1.0	11.5	ns
	MR to Q7S	Figure 1 $C_L = 15pF$	4.5V to 5.5V	=	4.6	8.2	1.0	9.5	1.0	10.5	ns
	MR to Q75	Figure 1 $C_L = 50pF$	4.5V to 5.5V	=	5.8	10.5	1.0	11.5	1.0	12.5	115
t <sub>EN</sub>	<del></del>	Figure 1 C <sub>L</sub> = 15pF	4.5V to 5.5V	-	4.8	9	1.0	11	1.0	12	
Enable Time	OE to Qn	Figure 1 C <sub>L</sub> = 50pF	4.5V to 5.5V	-	6.2	11.6	1.0	13	1.0	14.5	ns
tois	<u> </u>	Figure 1 C <sub>L</sub> = 15pF	4.5V to 5.5V	-	3.6	6.9	1.0	8	1.0	9	
Disable Time	OE to Qn	Figure 1 $C_L = 50pF$	4.5V to 5.5V	-	5.8	10.3	1.0	11	1.0	12	ns

## Operating Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Parameter		Test Conditions	V <sub>CC</sub> = 5V Typ	Unit
C <sub>pd</sub>	Power dissipation capacitance	f = 1 MHz all outputs switching-no load	42	pF

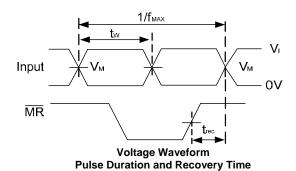


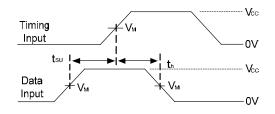
### **Parameter Measurement Information**



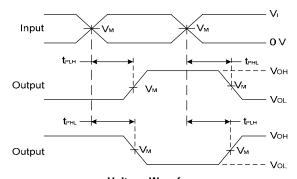
TEST	Vload
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>CC</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

V	Vec		V	м	C	
V <sub>CC</sub>	Vı	t <sub>r</sub> /t <sub>f</sub>	Input	Output	CL	
4.5V to 5.5V	3.0V	3ns	1.5V	V <sub>CC</sub> /2	15pF, 50pF	

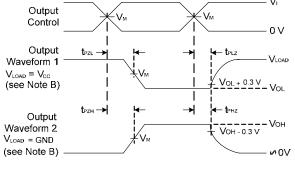




Voltage Waveform Set-up and Hold Times



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times

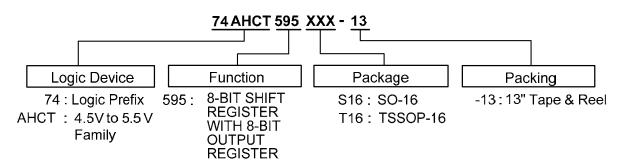
Notes:

- A. Includes test lead and test apparatus capacitance.
- B. Output Waveform 1 depends on the internal Q<sub>N</sub> node being low and behaves in this manner based on OE pin. Output Waveform 2 depends on the internal Q<sub>N</sub> node being high and behaves in this manner based on OE pin.
- C. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- D. Inputs are measured separately one transition per measurement.
- E. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>PD</sub>.

Figure 1 Load Circuit and Voltage Waveforms



### **Ordering Information**

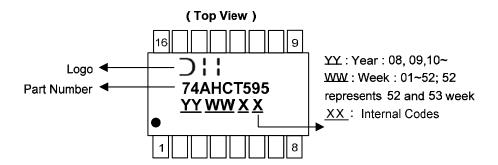


Part Number	Dookses Code	Dookoaina	7" Tape and	Reel (Note 6)
Part Number	Package Code	Packaging	Quantity	Part Number Suffix
74AHCT595S16-13	S16	SO-16	2500/Tape & Reel	-13
74AHCT595T16-13	T16	TSSOP-16	2500/Tape & Reel	-13

Note: 6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

### **Marking Information**

#### (1) SO-16, TSSOP16



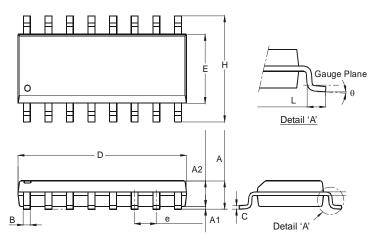
Part Number	Package
74AHCT595S16	SO-16
74AHCT595T16	TSSOP-16



## Package Outline Dimensions (All dimensions in mm.)

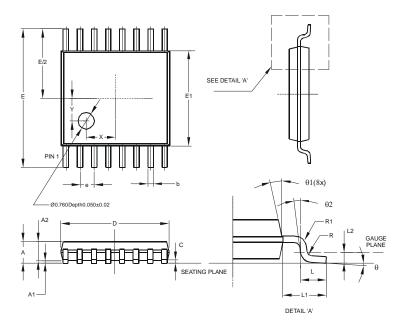
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

### Package Type: SO-16



	SO-16							
Dim	Min	Max						
Α	1.40	1.75						
A1	0.10	0.25						
A2	1.30	1.50						
В	0.33	0.51						
O	0.19	0.25						
ם	9.80	10.00						
ш	3.80	4.00						
e	1.27	Тур						
Η	5.80	6.20						
L	0.38	1.27						
Θ	0°	8°						
All D	All Dimensions in mm							

### Package Type: TSSOP-16



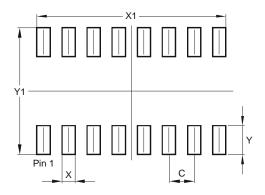
TSSOP-16				
Dim	Min	Max	Тур	
Α	-	1.08	-	
A1	0.05	0.15	-	
A2	0.80	0.93	-	
b	0.19	0.30	-	
C	0.09	0.20	-	
ם	4.90	5.10	-	
ш	6.40 BSC			
E1	4.30	4.50	-	
е	0.65 BSC			
L	0.45	0.75	-	
L1	1.00 REF			
L2	0.25 BSC			
R	0.09	-	-	
R1	0.09	1	-	
X	1	1	1.350	
Υ	-	-	1.050	
Θ	0°	8°	-	
Θ1	5°	15°	-	
Θ2	0°	-	-	
All Dimensions in mm				



## **Suggested Pad Layout**

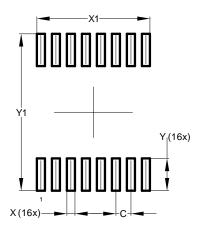
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

### Package Type: SO-16



Dimensions	Value (in mm)	
С	1.270	
Х	0.670	
X1	9.560	
Y	1.450	
Y1	6.400	

### Package Type: TSSOP-16



Dimensions	Value (in mm)	
С	0.650	
Х	0.350	
X1	4.900	
Υ	1.400	
Y1	6.800	



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NLU3G16AMX1TCG NLV27WZ125USG MC74HCT365ADTR2G BCM6306KMLG 54FCT240CTDB Le87401NQC Le87402MQC
028192B 042140C 051117G 070519XB 065312DB 091056E 098456D NL17SG07DFT2G NL17SG17DFT2G NL17SG34DFT2G
NL17SZ07P5T5G NL17SZ125P5T5G NLU1GT126AMUTCG NLV27WZ16DFT2G 5962-8982101PA 5962-9052201PA 74LVC07ADR2G
MC74VHC1G125DFT1G NL17SH17P5T5G NL17SZ125CMUTCG NLV17SZ07DFT2G NLV37WZ17USG NLVHCT244ADTR2G
NC7WZ17FHX 74HCT126T14-13 NL17SH125P5T5G NLV14049UBDTR2G NLV37WZ07USG 74VHC541FT(BE) RHFAC244K1
74LVC1G17FW4-7 74LVC1G126FZ4-7 BCM6302KMLG 74LVC1G07FZ4-7 74LVC1G125FW4-7